# CEL NEC'S NPN SILICON TRANSISTOR

NE681M13

#### FEATURES

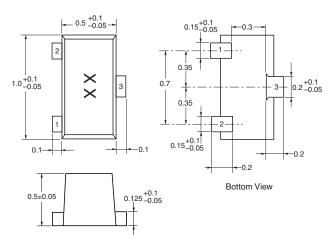
- NEW MINIATURE M13 PACKAGE:
  - Small transistor outline -
  - 1.0 X 0.5 X 0.5 mm
  - Low profile / 0.50 mm package height
  - Flat lead style for better RF performance
- HIGH GAIN BANDWIDTH PRODUCT:
  ft = 7 GHz
- · LOW NOISE FIGURE:
  - NF = 1.4 dB

### DESCRIPTION

NEC's NE681M13 transistor is ideal for low noise, high gain, and low cost amplifier applications. NEC's new low profile/ flat lead style "M13" package is ideal for today's portable wireless applications. The NE681 is also available in chip, Micro-x, and six different low cost plastic surface mount package styles.

#### OUTLINE DIMENSIONS (Units in mm)

#### PACKAGE OUTLINE M13



**PIN CONNECTIONS** 

- 1. Emitter
- 2. Base
- 3. Collector

#### ELECTRICAL CHARACTERISTICS (TA = 25°C)

PART NUMBER EIAJ <sup>1</sup> REGISTERED NUMBER PACKAGE OUTLINE			NE681M13 2SC5615 M13			
SYMBOLS	PARAMETERS AND CONDITIONS	UNITS	MIN	ТҮР	МАХ	
fτ	Gain Bandwidth at VCE = 3 V, IC = 7 mA, f = 1 GHz	GHz	4.5	7		
NF	Noise Figure at Vce = 3 V, Ic = 7 mA, f = 1 GHz	dB		1.4	2.7	
IS21El <sup>2</sup>	Insertion Power Gain at Vce = 3 V, Ic = 7 mA, f = 1 GHz	dB	10	12		
hfe <sup>2</sup>	Forward Current Gain at VcE = 3 V, Ic = 7 mA		80		145	
Ісво	Collector Cutoff Current at VCB = 10 V, IE = 0	μΑ			0.8	
Іево	Emitter Cutoff Current at VEB = 1 V, IC = 0	μΑ			0.8	
CRE <sup>3</sup>	Feedback Capacitance at $V_{CB} = 3 V$ , $I_E = 0$ , $f = 1 MHz$	pF			0.9	

Notes:

1. Electronic Industrial Association of Japan.

2. Pulsed measurement, pulse width  $\leq$  350 µs, duty cycle  $\leq$  2 %.

3. Capacitance is measured with emitter and case connected to the guard terminal at the bridge.

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SYMBOLS	PARAMETERS	UNITS	RATINGS
Vсво	Collector to Base Voltage	V	20
VCEO	Collector to Emitter Voltage	V	10
VEBO	Emitter to Base Voltage	V	1.5
lc	Collector Current	mA	65
PT <sup>2</sup>	Total Power Dissipation	mW	140
TJ	Junction Temperature	°C	150
Tstg	Storage Temperature	°C	-65 to +150

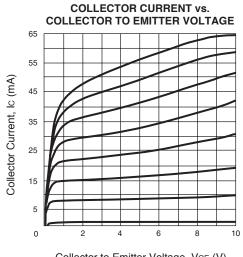
#### ABSOLUTE MAXIMUM RATINGS<sup>1</sup> (TA = 25°C)

Notes:

1. Operation in excess of any one of these parameters may result in permanent damage.

2. With device mounted on 1.08 cm<sup>2</sup> X 1.2 mm glass epoxy board.

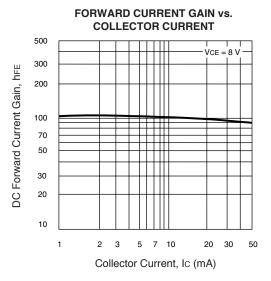
#### TYPICAL PERFORMANCE CURVES (TA = 25°C)



Collector to Emitter Voltage, VCE (V)

#### **ORDERING INFORMATION**

PART NUMBER	QUANTITY
NE681M13-A	
NE681M13-T3-A	



Life Support Applications

These NEC products are not intended for use in life support devices, appliances, or systems where the malfunction of these products can reasonably be expected to result in personal injury. The customers of CEL using or selling these products for use in such applications do so at their own risk and agree to fully indemnify CEL for all damages resulting from such improper use or sale.

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Subject: Compliance with EU Directives

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CEL Pb-free products have the same base part number with a suffix added. The suffix –A indicates that the device is Pb-free. The –AZ suffix is used to designate devices containing Pb which are exempted from the requirement of RoHS directive (\*). In all cases the devices have Pb-free terminals. All devices with these suffixes meet the requirements of the RoHS directive.

This status is based on CEL's understanding of the EU Directives and knowledge of the materials that go into its products as of the date of disclosure of this information.

Restricted Substance per RoHS	Concentration Limit per RoHS (values are not yet fixed)	Concentration contained in CEL devices	
Lead (Pb)	< 1000 PPM	-A Not Detected	-AZ (*)
Mercury	< 1000 PPM	Not Detected	
Cadmium	< 100 PPM	Not Detected	
Hexavalent Chromium	< 1000 PPM	Not Detected	
РВВ	< 1000 PPM	Not Detected	
PBDE	< 1000 PPM	Not Detected	

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